Pb Free Plating Product

GF2045MC thru GF20200MC

20.0 Ampere Surface Mount PhotoVoltaic Bypass Schottky Barrier Rectifier

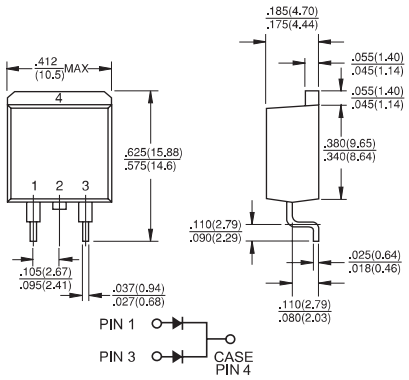
Features

- For surface mounted application
- Plastic material used carries Underwriters Laboratory Classifications 94V-0
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- Guardring for overvoltage protection
- High temperature soldering guaranteed: 260°C/10 seconds at terminals

Mechanical Data

- Cases: JEDEC D²PAK /TO-263-2L molded plastic
- Terminals: Pure tin plated, lead free. solderable per MIL-STD-750, Method 2026
- Polarity: As marked
- Mounting position: Any
- Mounting torque: 5 in. - lbs. max
- Weight: 0.06 ounce, 1.70 grams

D²PAK



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%

Type Number	Symbol	GF2045MC	GF2060MC	GF20100MC	GF20200MC	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	45	60	100	200	V
Maximum RMS Voltage	V_{RMS}	31	42	70	140	V
Maximum DC Blocking Voltage	V_{DC}	45	60	100	200	V
Maximum Average Forward Rectified Current at T_C=135°C	$I_{(AV)}$	20				A
Peak Repetitive Forward Current (Rated V_R, Square Wave, 20KHz) at Tc=135°C	I_{FRM}	20				A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	150				A
Peak Repetitive Reverse Surge Current (Note 1)	I_{RRM}	1.0	0.5			A
Maximum Instantaneous Forward Voltage at (Note 2) IF=10A, TC=25°C IF=10A, TC=125°C IF=20A, TC=25°C IF=20A, TC=125°C	V_F	– 0.57 0.84 0.72	0.80 0.70 0.95 0.85	0.85 0.75 0.95 0.85	0.99 0.87 1.23 1.10	V
Maximum Instantaneous Reverse Current @ Tc=25℃	I_R	0.1	0.1			mA
at Rated DC Blocking Voltage @ Tc=125℃		15	10	5.0		mA
Voltage Rate of Change, (Rated V_R)	dV/dt	10,000				V/uS
Typical Junction Capacitance	Cj	400	320			pF
Typical Thermal Resistance Per Leg (Note 3)	$R_{\theta JC}$	1.0		2.0		°C/W
Operating Junction Temperature Range	T_J	-65 to +150				°C
Storage Temperature Range	TSTG	-65 to +175				°C

Notes: 1. 2.0us Pulse Width, f=1.0 KHz
2. Pulse Test: 300us Pulse Width, 1% Duty Cycle
3. Thermal Resistance from Junction to Case Per Leg, with Heatsink Size (4"x6"x0.25") Al-Plate.

FIG.1- FORWARD CURRENT DERATIN CURVE

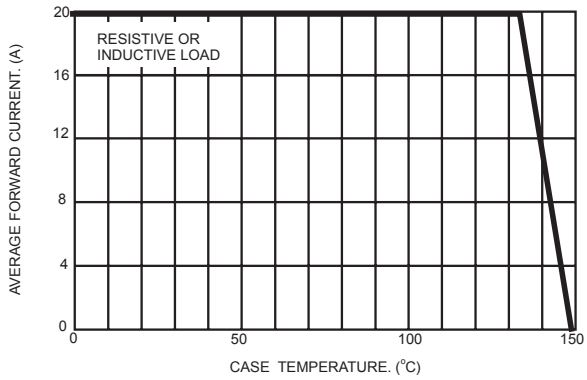


FIG.2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PER LEG

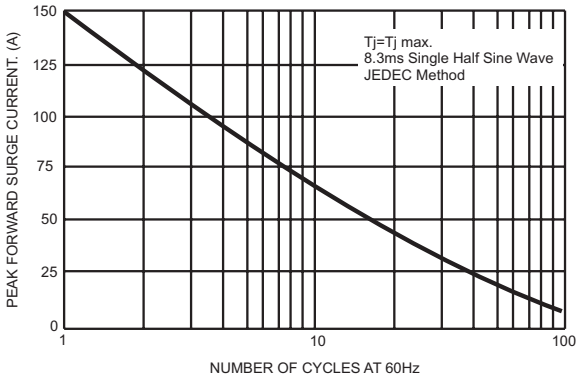


FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS PER LEG

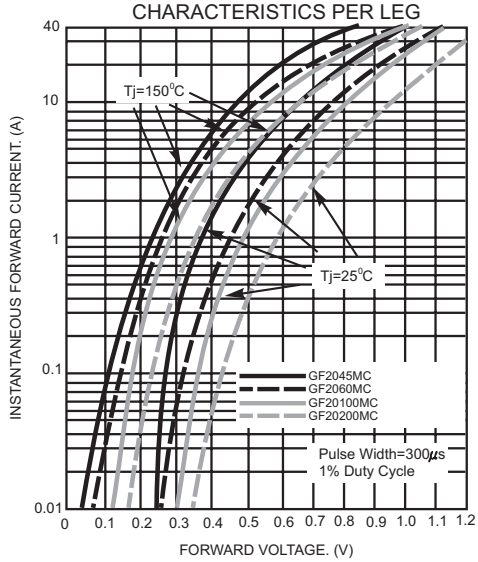


FIG.4- TYPICAL REVERSE CHARACTERISTICS PER LEG

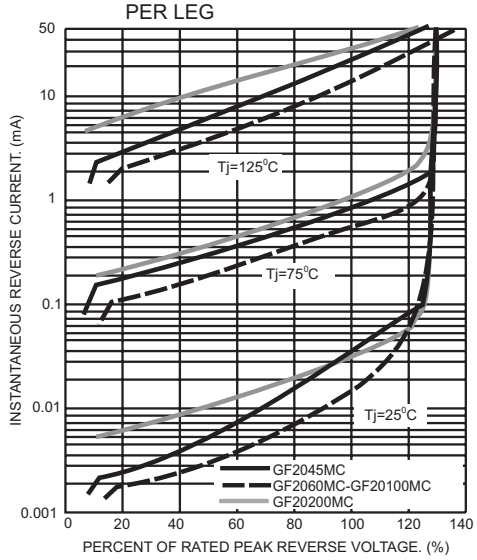


FIG.5- TYPICAL JUNCTION CAPACITANCE PER LEG

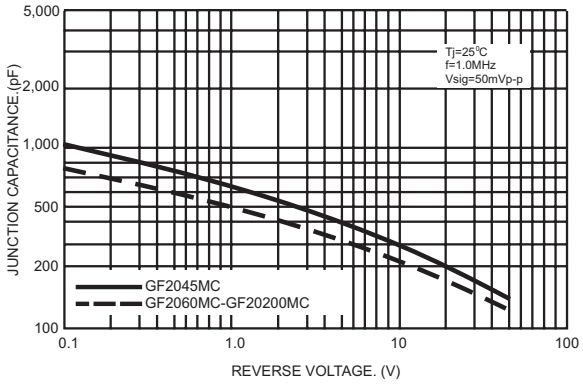


FIG.6- TYPICAL TRANSIENT THERMAL IMPEDANCE PER LEG